

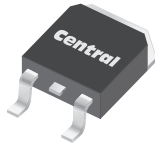
CJD44H11 NPN
CJD45H11 PNP

**SURFACE MOUNT SILICON
COMPLEMENTARY
POWER TRANSISTORS**



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DPAK POWER!



DPAK CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CJD44H11 and CJD45H11 are complementary silicon power transistors manufactured in a surface mount package, and designed for switching and power amplifier applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL		UNITS
Collector-Emitter Voltage	V_{CEO}	80	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Continuous Collector Current	I_C	8.0	A
Peak Collector Current	I_{CM}	16	A
Power Dissipation	P_D	20	W
Power Dissipation ($T_A=25^\circ\text{C}$)	P_D	1.75	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Thermal Resistance	θ_{JC}	6.25	$^\circ\text{C}/\text{W}$
Thermal Resistance	θ_{JA}	71.4	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CES}	$V_{CE}=80\text{V}$			10	μA
I_{EBO}	$V_{EB}=5.0\text{V}$			50	μA
BV_{CEO}	$I_C=30\text{mA}$	80			V
$V_{CE(SAT)}$	$I_C=8.0\text{A}, I_B=400\text{mA}$			1.0	V
$V_{BE(SAT)}$	$I_C=8.0\text{A}, I_B=800\text{mA}$			1.5	V
h_{FE}	$V_{CE}=1.0\text{V}, I_C=2.0\text{A}$	60			
h_{FE}	$V_{CE}=1.0\text{V}, I_C=4.0\text{A}$	40			
f_T	$V_{CE}=10\text{V}, I_C=500\text{mA}, f=20\text{MHz}$ (CJD44H11)		60		MHz
f_T	$V_{CE}=10\text{V}, I_C=500\text{mA}, f=20\text{MHz}$ (CJD45H11)		50		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=0.1\text{MHz}$ (CJD44H11)		120		pF
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=0.1\text{MHz}$ (CJD45H11)		220		pF
$t_d + t_r$	$I_C=5.0\text{A}, I_{B1}=500\text{mA}$ (CJD44H11)		320		ns
$t_d + t_r$	$I_C=5.0\text{A}, I_{B1}=500\text{mA}$ (CJD45H11)		150		ns
t_s	$I_C=5.0\text{A}, I_{B1}=I_{B2}=500\text{mA}$		450		ns
t_f	$I_C=5.0\text{A}, I_{B1}=I_{B2}=500\text{mA}$ (CJD44H11)		130		ns
t_f	$I_C=5.0\text{A}, I_{B1}=I_{B2}=500\text{mA}$ (CJD45H11)		100		ns

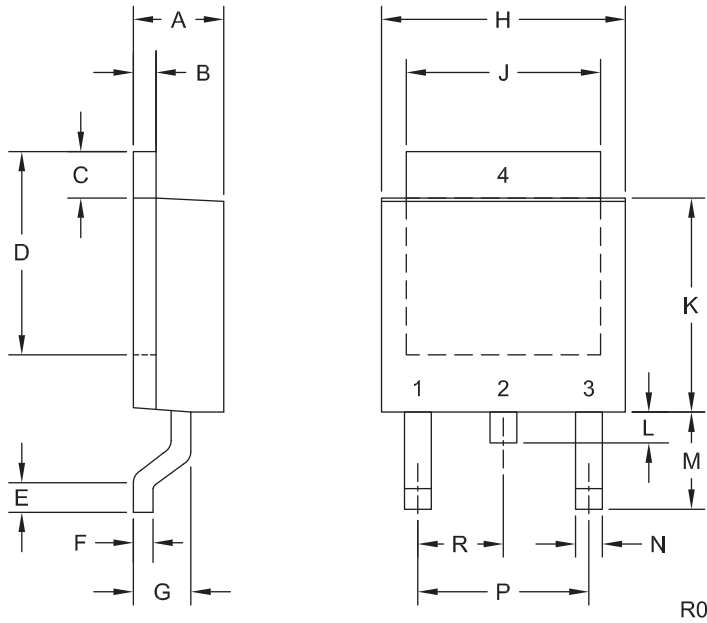
R3 (21-January 2013)

CJD44H11 NPN
CJD45H11 PNP



**SURFACE MOUNT SILICON
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DPAK CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Base
- 2) Collector
- 3) Emitter
- 4) Collector

MARKING:

FULL PART NUMBER

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.083	0.108	2.10	2.75
B	0.016	0.032	0.40	0.81
C	0.035	0.063	0.89	1.60
D	0.203	0.228	5.15	5.79
E	0.020	-	0.51	-
F	0.018	0.024	0.45	0.60
G	0.051	0.071	1.30	1.80
H	0.248	0.268	6.30	6.81
J	0.197	0.217	5.00	5.50
K	0.209	0.245	5.30	6.22
L	0.025	0.040	0.64	1.02
M	0.090	0.115	2.30	2.91
N	0.012	0.045	0.30	1.14
P	0.180		4.60	
R	0.090		2.30	

DPAK (REV: R0)

R3 (21-January 2013)

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- Application notes
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